












Ceramic transient voltage suppressors

Selector guide

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Selector guide

Design	Technology	Construction	Case size	Terminals	Code		Page
Multilayer varistors (MLVs)							
SMD	Multilayer	Single chip	0201, 0402, 0603, 0805, 1206, 1210, 1812, 2220	Nickel barrier metallization	CT		
				Silver-palladium metallization	CN		
				Silver-platinum metallization	CN... K2		
		2-fold array	0405	Nickel barrier metallization	CA		
	4-fold array	0508, 0612					
ESD/EMI filters							
SMD	Multilayer	2-fold array with common ground	0405	Nickel barrier metallization	CA		
		4-fold array with common ground	0508				
CeraDiodes							
SMD	Multilayer	Single chip	0201, 0402, 0603, 1003	Nickel barrier metallization	CDS		
		4-fold array	0508, 0612	Nickel barrier metallization	CDA		
		2/4 data + 1 supply array	0506, 1012				
SMD disk varistors (CU varistors)							
SMD	Monolithic	Disk varistor element with thermoplast encapsulation	3225, 4032	Tinned copper alloy	CU		
Leaded transient voltage/RFI suppressors (SHCVs)							
Leaded	Multilayer	Multilayer varistor plus multilayer capacitor	SR1, SR2, SR6	Tinned iron wire	SR	